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DUAL DIGIT LED DISPLAY (0.25Inch)

LDD215/62-XX/F1

DATA SHEET

DOC. NO : QW0905-LDD215/62-XX/F1

REV. : A

DATE : 16- May. - 2005



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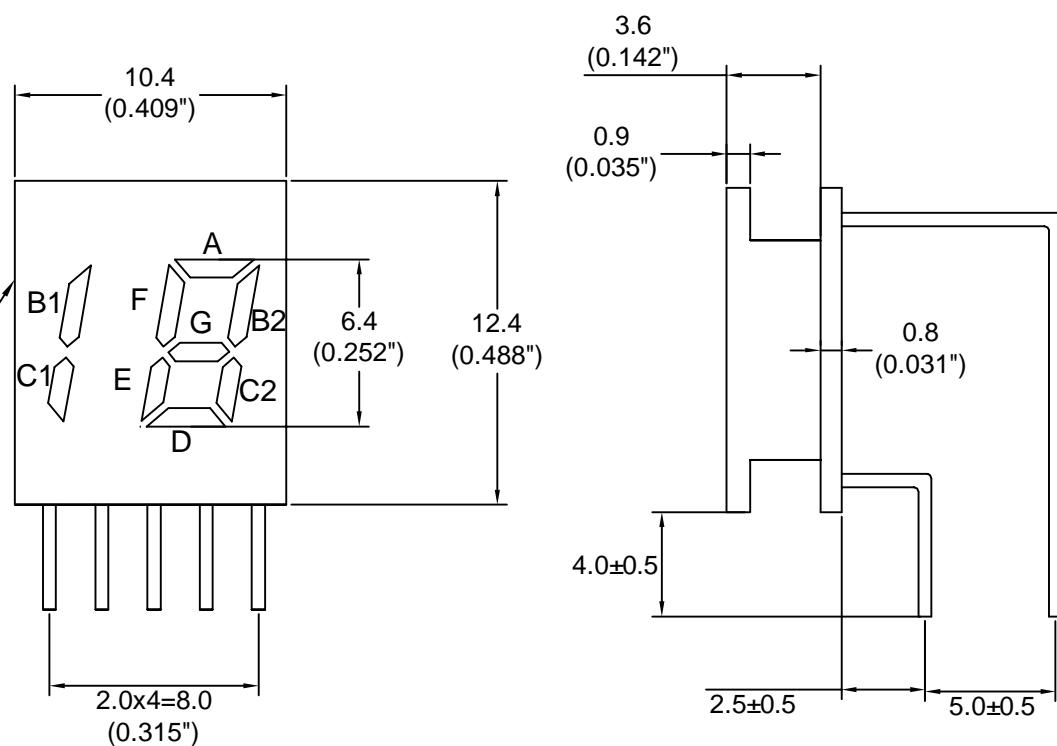
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Package Dimensions

LDD215/62-XX/F1
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PIN NO.1 →

Note : 1. All dimension are in millimeters and (Inch) tolerance is $\pm 0.25\text{mm}$ unless otherwise noted.
2. Specifications are subject to change without notice.



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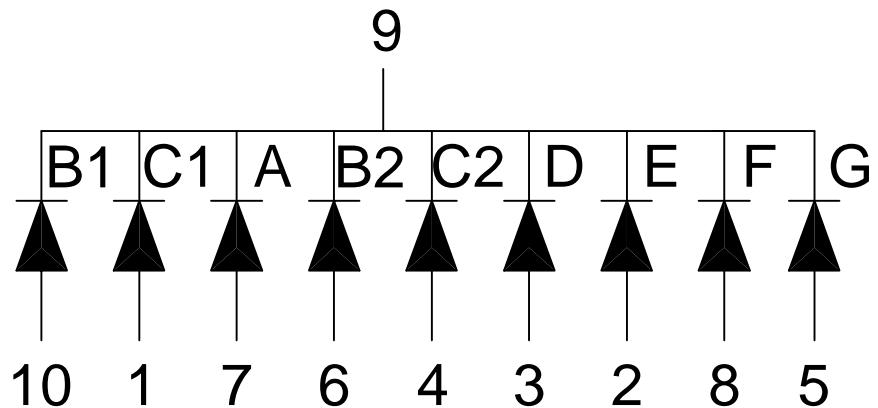
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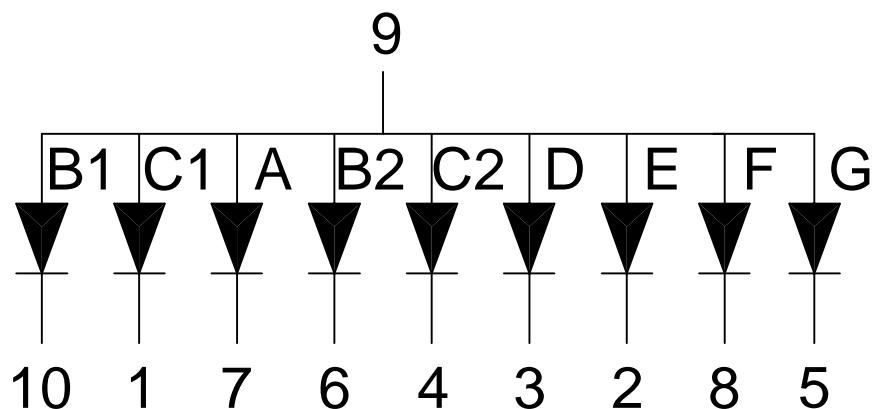
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Internal Circuit Diagram

LDD2152-XX/F1



LDD2162-XX/F1





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Electrical Connection

PIN NO.1	LDD2152-XX/F1	PIN NO.1	LDD2162-XX/F1
1	Anode C1	1	Cathode C1
2	Anode E	2	Cathode E
3	Anode D	3	Cathode D
4	Anode C2	4	Cathode C2
5	Anode G	5	Cathode G
6	Anode B2	6	Cathode B2
7	Anode A	7	Cathode A
8	Anode F	8	Cathode F
9	Common Cathode	9	Common Anode
10	Anode B1	10	Cathode B1



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Absolute Maximum Ratings at Ta=25

Parameter	Symbol	Ratings		UNIT
		G		
Forward Current Per Chip	IF	30		mA
Peak Forward Current Per Chip (Duty 1/10,0.1ms Pulse Width)	IFP	120		mA
Power Dissipation Per Chip	PD	100		mW
Reverse Current Per Any Chip	Ir	10		µ A
Operating Temperature	Topr	-25 ~ +85		
Storage Temperature	Tstg	-25 ~ +85		
Solder Temperature 1-16 Inch Below Seating Plane For 3 Seconds At 260				

Part Selection And Application Information(Ratings at 25)

PART NO	CHIP		common cathode or anode	P (nm)	(nm)	Electrical				IV-M
						Vf(v)		Iv(mcd)		
	Material	Emitted				Min.	Typ.	Max.	Min.	Typ.
LDD2152-XX/F1	GaP	Red	Common Anode	565	30	1.7	2.1	2.6	0.05	0.08
LDD2162-XX/F1			Common Cathode							

Note : 1.The forward voltage data did not including ±0.1V testing tolerance.
 2. The luminous intensity data did not including ±15% testing tolerance.



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Test Condition For Each Parameter

Parameter	Symbol	Unit	Test Condition
Forward Voltage Per Chip	Vf	volt	If=20mA
Luminous Intensity Per Chip	Iv	mcd	If=10mA
Peak Emission Wavelength	P	nm	If=20mA
Spectral Line Half-Width		nm	If=20mA
Reverse Current Any Chip	Ir	μ A	Vr=5V
Luminous Intensity Matching Ratio	IV-M		



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Typical Electro-Optical Characteristics Curve

G CHIP

Fig.1 Forward current vs. Forward Voltage

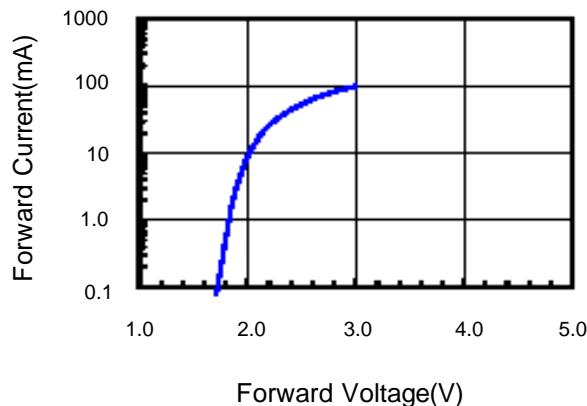


Fig.2 Relative Intensity vs. Forward Current

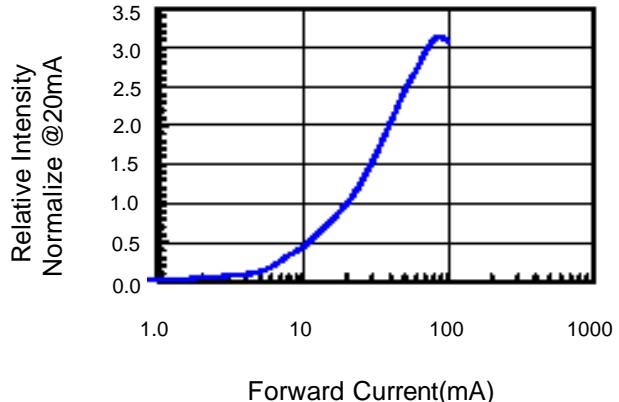


Fig.3 Forward Voltage vs. Temperature

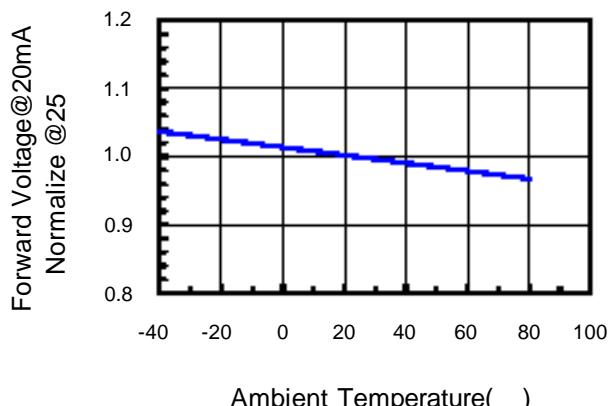


Fig.4 Relative Intensity vs. Temperature

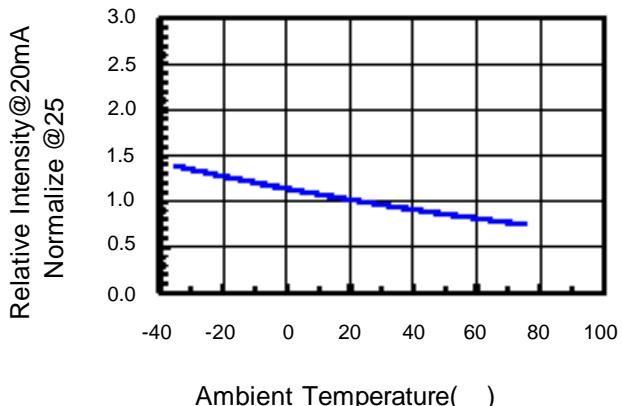
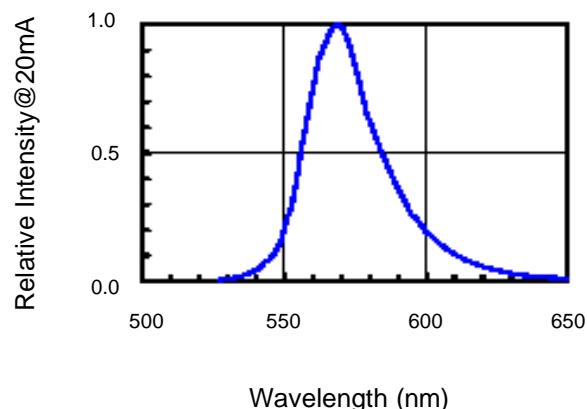


Fig.5 Relative Intensity vs. Wavelength





Reliability Test:

Test Item	Test Condition	Description	Reference Standard
Operating Life Test	1.Under Room Temperature 2.If=10mA 3.t=1000 hrs (-24hrs, +72hrs)	This test is conducted for the purpose of determining the resistance of a part in electrical and thermal stressed.	MIL-STD-750: 1026 MIL-STD-883: 1005 JIS C 7021: B-1
High Temperature Storage Test	1.Ta=105 ±5 2.t=1000 hrs (-24hrs, +72hrs)	The purpose of this is the resistance of the device which is laid under condition of high temperature for hours.	MIL-STD-883:1008 JIS C 7021: B-10
Low Temperature Storage Test	1.Ta=-40 ±5 2.t=1000 hrs (-24hrs, +72hrs)	The purpose of this is the resistance of the device which is laid under condition of low temperature for hours.	JIS C 7021: B-12
High Temperature High Humidity Test	1.Ta=65 ±5 2.RH=90%~95% 3.t=240hrs ±2hrs	The purpose of this test is the resistance of the device under tropical for hours.	MIL-STD-202:103B JIS C 7021: B-11
Thermal Shock Test	1.Ta=105 ±5 &-40 ±5 (10min) (10min) 2.total 10 cycles	The purpose of this is the resistance of the device to sudden extreme changes in high and low temperature.	MIL-STD-202: 107D MIL-STD-750: 1051 MIL-STD-883: 1011
Solder Resistance Test	1.T.Sol=260 ±5 2.Dwell time= 10 ±1sec.	This test intended to determine the thermal characteristic resistance of the device to sudden exposures at extreme changes in temperature when soldering the lead wire.	MIL-STD-202: 210A MIL-STD-750: 2031 JIS C 7021: A-1
Solderability Test	1.T.Sol=230 ±5 2.Dwell time=5 ±1sec	This test intended to see soldering well performed or not.	MIL-STD-202: 208D MIL-STD-750: 2026 MIL-STD-883: 2003 JIS C 7021: A-2